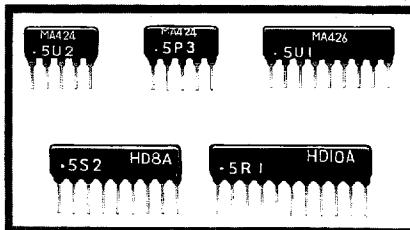


Diode Arrays

High-speed switching diode arrays and high voltage-withstand diode arrays are of NICHICON's standard series. They are combined to be conveniently used for both binary and decimal systems. High-speed series is ideal for computer peripherals, control boards and general electronic appliances. Besides, high voltage-withstand series is ideal for plasma displays, relay surge-preventive circuits.

Both of these series are in stock for prompt delivery. Any special requirements with customer's particular circuits will be also welcome. Please consult us for the details.

(Samples for the items listed below are not always available on stock. please contact our sales office for details together with your specific requirements.)



■ High-speed switching diode array series

● Absolute maximum ratings *

Items	Symbol	Ratings
Peak reverse voltage	V _{RM}	40V
DC reverse voltage	V _R	40V
Surge current(1 μ s)	I _{FSM}	4.0A
Peak forward current	I _{FM}	300mA
Average rectified current	I _o	150mA*
Storage temperature	T _{tsg}	-25~+85°C

* 100mA for simultaneous energizing.

* Maximum Current value applicable to each diode.

● Electrical characteristics

T_a : +25°C

Items	Symbol	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
Reverse current	I _R	V _R =40V	—	—	0.5	μA
Forward voltage	V _{F1}	I _F =10mA	—	0.7	1.0	V
Forward voltage	V _{F2}	I _F =50mA	—	0.79	1.0	V
Forward voltage	V _{F3}	I _F =100mA	—	0.85	1.2	V
Reverse recovery time	trr	I _F =10mA, V _R =6V	—	—	4.0	nS

● Series List

Code	Type	Number of diodes	Common electrode	Dimensions (%Max.)			No. of Pins n	Circuit diagram		
				W	H	T		①	②	③
ZHMA0423	MA423	4	Cathode	14	9	3.5	5	①	②	③
ZHMA0424	MA424		Anode							
ZHMA0425	MA425	8	Cathode	24	9	3.5	9	①	②	③
ZHMA0426	MA426		Anode							
ZHMA0427	MA427	10	Cathode	29	9	3.5	11	①	②	③
ZHMA0428	MA428		Anode							
ZHMA0429	MA429	5	Isolated	27	9	3.5	10	③		
ZHMA0430	MA430	4	Isolated	21.5	9	3.5	8	③		
ZHMA0431	MA431	6	Cathode	19	9	3.5	7	①	②	③
ZHMA0432	MA432		Anode							

■ High voltage-withstand series

● Absolute maximum ratings *

Items	Symbol	Ratings
Peak reverse voltage	V _{RM}	220V
Reverse DC voltage	V _R	200V
Surge current (1 sec.)	I _s	1A
Peak forward current	I _{FM}	600mA
Average rectified current	I _o	200mA
Storage temperature	T _{tsg}	-25~+85°C

* Maximum Current value applicable to each diode.

T_a : +25°C

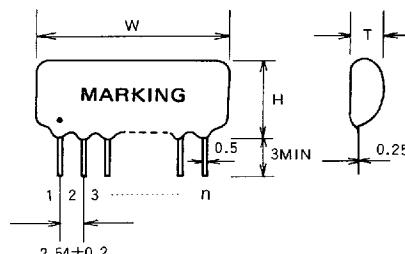
● Electrical characteristics

Items	Symbol	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
Reverse current	I _R	V _R =110V	—	—	1.0	μA
Forward voltage	V _F	I _F =50mA	—	—	—	V
Reverse voltage	V _R	I _r =100μA	220	—	—	V
Time required for recovery from reverse voltage or current	trr	I _r =I _F =30mA	—	—	100	ns
				R _L =100Ω		

● Series List

Code	Type	Number of diodes	Common electrode	Dimensions (%Max.)			No. of Pins n	Circuit diagram		
				W	H	T		①	②	③
ZHLA0650	HD-4K	4	Cathode	14	9	3	5	①	②	③
ZHLA0651	HD-4A		Anode							
ZHLA0652	HD-8K	8	Cathode	24	9	3	9	①	②	③
ZHLA0653	HD-8A		Anode							
ZHLA0654	HD-10K	10	Cathode	29	9	3	11	①	②	③
ZHLA0655	HD-10A		Anode							
ZHLA0656	HD-4S	4	Isolated	21.5	9	3	8	③		
ZHLA0657	HD-5S	5	Isolated	27	9	3	10	③		

● Drawing



• Epoxy-resin coating
• Iron lead frame, tin-plated over copper

RD Arrays

● Series List

Code	Type	Common electrode	Specifications			Dimensions (%Max.)	No. of pins n	Circuit diagram
			Resistor	Diode	Resistance			
ZHMA2401	MA2401	Anode	8	8	330Ω	± 5 %	60mW	24.5 7 4 9
ZHMA2402	MA2402	Anode	8	8	1kΩ	± 5 %	60mW	24.5 7 4 9

Diode Mini-Arrays

• Height.....5mm Max.

The mounting height of electronic device can be made substantially low-profile and compact.

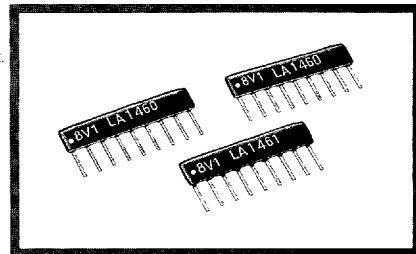
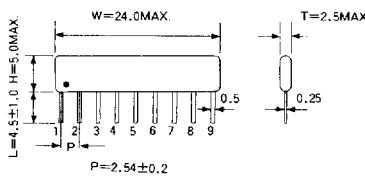
• Thickness.....2.5mm Max.

Diode arrays can be placed in a row with 2.54mm pitch, and high density mounting is available at a rate of one diode per 0.1 sq. inch.

• Electrical characteristics

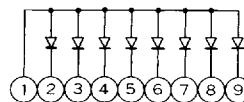
Items	Symbol	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
Reverse current	I_R	$V_R=35V$	—	—	0.5	μA
Forward voltage	V_{F1}	$I_F=10mA$	—	0.75	1.0	V
Forward voltage	V_{F2}	$I_F=50mA$	—	0.90	1.1	V
Forward voltage	V_{F3}	$I_F=100mA$	—	0.95	1.2	V
Reverse recovery time	t_{rr}	$I_F=10mA, V_R=6V$	—	—	4.0	ns

• Drawing

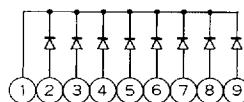


• Circuit diagram

ZHLA1460



ZHLA1461



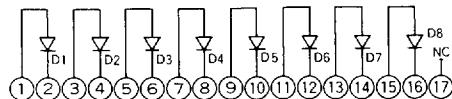
Any particular specifications are also available upon request.

Diode Arrays for Specific Layout

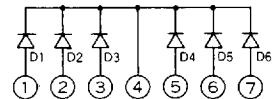
• Absolute maximum ratings

Items	Symbol	Ratings			Unit
		Min.	Typ.	Max.	
Peak reverse voltage	V_{RM}	—	40V	—	
DC reverse voltage	V_R	—	40V	—	
Surge current (μs)	I_{FSM}	—	4.0A	—	
Peak forward current	I_{FM}	—	300mA	—	
Average rectified current	I_o	—	100mA	—	
Storage temperature	T_{stg}	—	—25~+85°C	—	

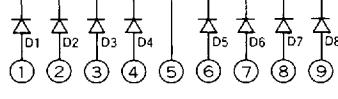
ZHMA2906 23.5^W×16^H×6^T (mm) (Fig. B)



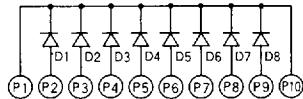
ZHMA2901 19^W×9^H×3.5^T (mm) (Fig. A)



ZHMA2911 24^W×9^H×3.5^T (mm) (Fig. A)



ZHMA2913 26.5^W×9^H×3.5^T (mm) (Fig. A)



• Drawing

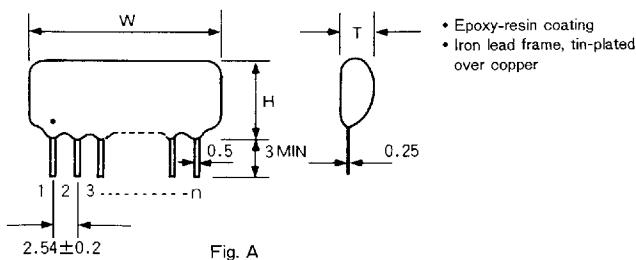
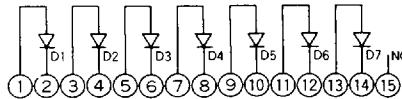


Fig. A

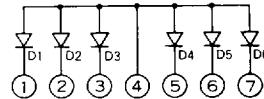
• Electrical characteristics

Items	Symbol	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
Reverse current	I_R	$VR=40V$	—	—	0.5	μA
Forward voltage	V_{F1}	$IF=10mA$	—	0.7	1.0	V
Forward voltage	V_{F2}	$IF=50mA$	—	0.79	1.0	V
Forward voltage	V_{F3}	$IF=100mA$	—	0.85	1.2	V
Reverse recovery time	t_{rr}	$IF=10mA, VR=6V$	—	—	4.0	nS

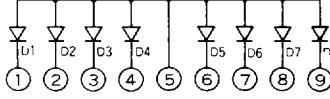
ZHMA2907 21^W×16^H×6^T (mm) (Fig. B)



ZHMA2902 19^W×9^H×3.5^T (mm) (Fig. A)



ZHMA2912 24^W×9^H×3.5^T (mm) (Fig. A)



ZHMA2914 26.5^W×9^H×3.5^T (mm) (Fig. A)

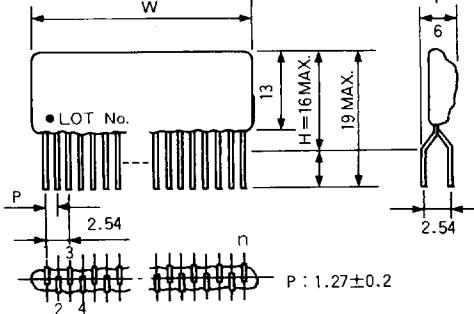
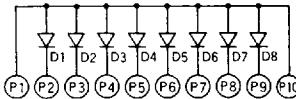


Fig. B

Cautions : Full care to be taken when solder flow applied to those miniature products.

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